

Maximum Ratings ($T_J = 25^\circ\text{C}$ unless otherwise noted)

| Rating | Symbol | Value | Unit |
|---|------------------------|-------------|--------------------|
| Peak Repetitive Off-State Voltage (Note 1) (Gate Open, Sine Wave 50 to 60 Hz, $T_J = -40^\circ$ to 110°C) | V_{DRM} V_{RRM} | 600 800 | V |
| On-State RMS Current (Full Cycle Sine Wave, 60 Hz, $T_C = 108^\circ\text{C}$) | I_T (RMS) | 4.0 | A |
| Peak Non-Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, $T_C = 108^\circ\text{C}$) | I_{TSM} | 40 | A |
| Circuit Fusing Consideration ($t = 8.3$ msec) | I^2t | 6.6 | A ² sec |
| Peak Gate Current (Pulse Width ≤ 20 μsec , $T_C = 108^\circ\text{C}$) | I_{GM} | 4.0 | A |
| Peak Gate Power (Pulse Width ≤ 10 μsec , $T_C = 108^\circ\text{C}$) | P_{GM} | 2.0 | W |
| Peak Gate Voltage (Pulse Width ≤ 20 μsec , $T_C = 108^\circ\text{C}$) | V_{GM} | 5.0 | V |
| Average Gate Power ($t = 8.3$ msec, $T_C = 108^\circ\text{C}$) | $P_{G(AV)}$ | 1.0 | W |
| Operating Junction Temperature Range | T_J | -40 to +125 | $^\circ\text{C}$ |
| Storage Temperature Range | T_{stg} | -40 to +150 | $^\circ\text{C}$ |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

Thermal Characteristics

| Rating | Symbol | Value | Unit |
|--|---|-----------------|---------------------------|
| Thermal Resistance Junction-to-Case (AC) Junction-to-Ambient Junction-to-Ambient (Note 2) | $R_{\theta JC}$ $R_{\theta JA}$ $R_{\theta JA}$ | 3.5 88 80 | $^\circ\text{C}/\text{W}$ |
| Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 10 seconds (Note 3) | T_L | 260 | $^\circ\text{C}$ |

- These ratings are applicable when surface mounted on the minimum pad sizes recommended.
- 1/8" from case for 10 seconds.

Electrical Characteristics - OFF ($T_J = 25^\circ\text{C}$ unless otherwise noted ; Electricals apply in both directions)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|--|------------------------|-----|-----|------|------|
| Peak Repetitive Blocking Current ($V_D = V_{DRM} = V_{RRM}$; Gate Open) | I_{DRM} I_{RRM} | - | - | 0.01 | mA |
| | | - | - | 2.0 | |

Electrical Characteristics - ON ($T_J = 25^\circ\text{C}$ unless otherwise noted; Electricals apply in both directions)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|---|--------------|-----|------|-----|------|
| Peak On-State Voltage (Note 4) ($I_{TM} = \pm 6.0$ A) | V_{TM} | - | 1.3 | 1.6 | V |
| Gate Trigger Current (Continuous dc) ($V_D = 12$ V, $R_L = 100$ Ω) | MT2(+), G(+) | 2.9 | 4.0 | 10 | mA |
| | MT2(+), G(-) | 2.9 | 5.0 | 10 | |
| | MT2(-), G(-) | 2.9 | 7.0 | 10 | |
| Holding Current ($V_D = 12$ V, Gate Open, Initiating Current = ± 200 mA) | I_H | 2.0 | 5.5 | 1.5 | mA |
| Latching Current | MT2(+), G(+) | - | 6.0 | 30 | mA |
| | MT2(+), G(-) | - | 10 | 30 | |
| | MT2(-), G(-) | - | 6.0 | 30 | |
| Gate Trigger Voltage (Continuous dc) ($V_D = 12$ V, $R_L = 100$ Ω) | MT2(+), G(+) | 0.5 | 0.7 | 1.3 | V |
| | MT2(+), G(-) | 0.5 | 0.65 | 1.3 | |
| | MT2(-), G(-) | 0.5 | 0.7 | 1.3 | |
| Gate Non-Trigger Voltage ($T_J = 125^\circ\text{C}$) ($V_D = 12$ V, $R_L = 100$ Ω) | MT2(+), G(+) | 0.2 | 0.4 | - | V |
| | MT2(+), G(-) | 0.2 | 0.4 | - | |
| | MT2(-), G(-) | 0.2 | 0.4 | - | |

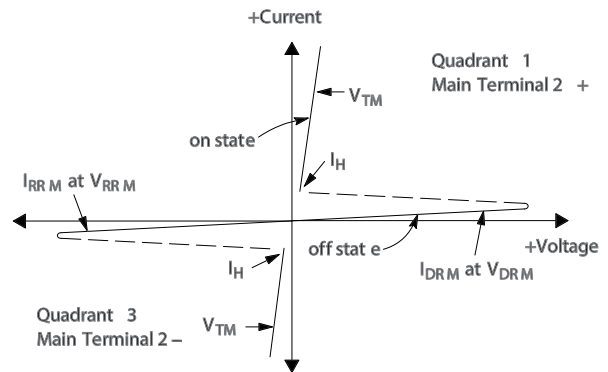
- Indicates Pulse Test: Pulse Width ≤ 2.0 ms, Duty Cycle $\leq 2\%$.

Dynamic Characteristics

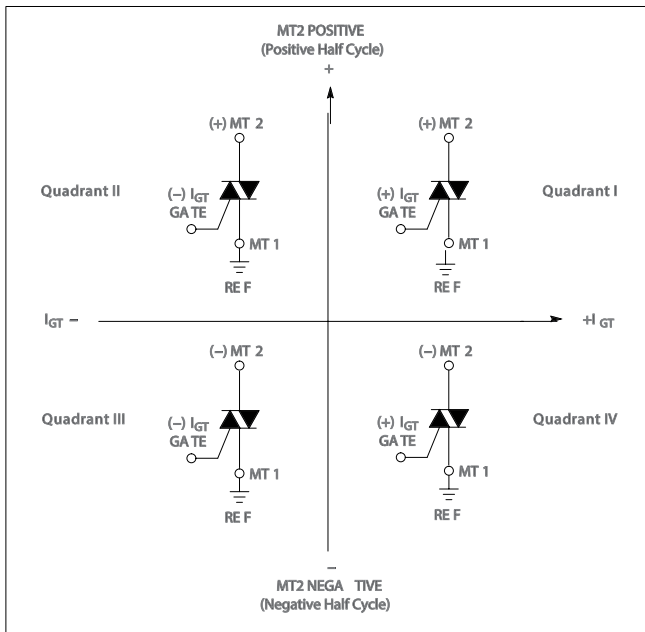
| Characteristic | Symbol | Min | Typ | Max | Unit |
|--|--------------------------|-----|-----|-----|------------------|
| Rate of Change of Commutating Current ($V_D = 400\text{ V}$, $I_{TM} = 3.5\text{ A}$, Commutating $dv/dt = 10\text{ V}/\mu\text{sec}$, Gate Open, $T_J = 125^\circ\text{C}$, $f = 500\text{ Hz}$, $CL = 5.0\ \mu\text{F}$, $LL = 20\text{ mH}$, No Snubber) See Figure 16 | (di/dt) _c | 3.0 | 4.0 | - | A/ms |
| Critical Rate of Rise of Off-State Voltage ($V_D = 0.67 \times V_{DRM}$, Exponential Waveform, Gate Open, $T_J = 125^\circ\text{C}$) | dV/dt | 50 | 175 | - | V/ μs |

Voltage Current Characteristic of SCR

| Symbol | Parameter |
|-----------|---|
| V_{DRM} | Peak Repetitive Forward Off State Voltage |
| I_{DRM} | Peak Forward Blocking Current |
| V_{RRM} | Peak Repetitive Reverse Off State Voltage |
| I_{RRM} | Peak Reverse Blocking Current |
| V_{TM} | Maximum On State Voltage |
| I_H | Holding Current |



Quadrant Definitions for a Triac



All polarities are referenced to MT1.
With in-phase signals (using standard AC lines) quadrants I and III are used

Figure 1. Typical RMS Current Derating

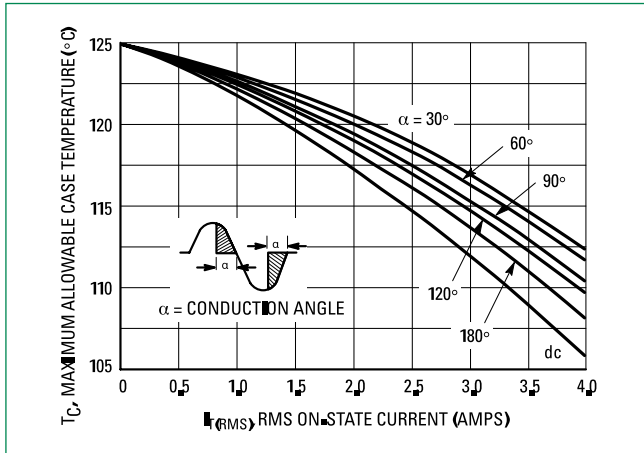


Figure 2. On-State Power Dissipation

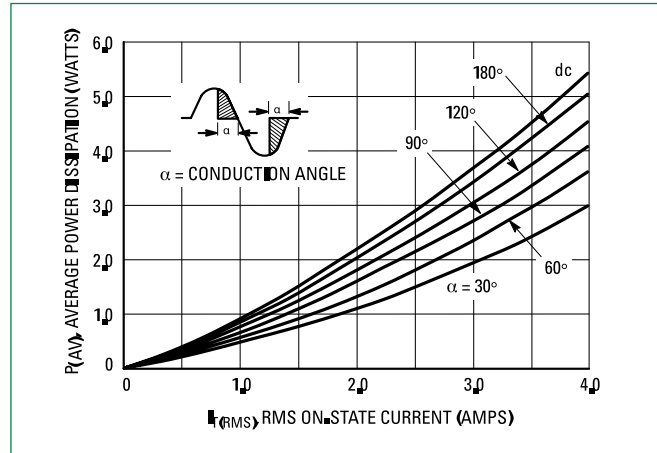


Figure 3. On-State Characteristics

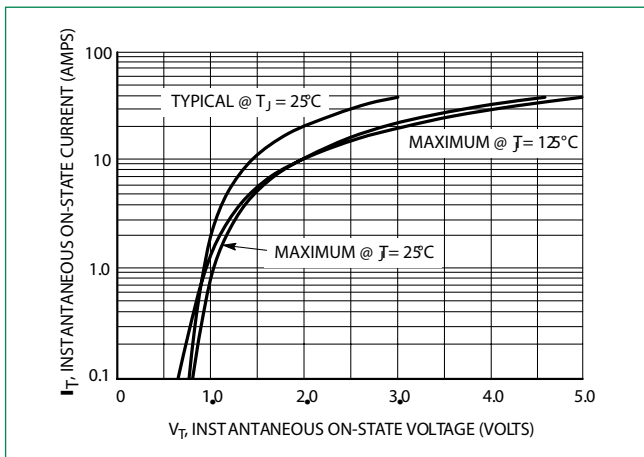


Figure 4. Transient Thermal Response

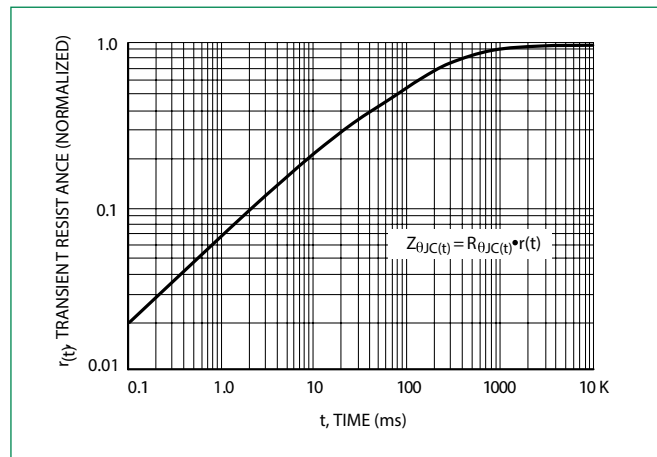


Figure 5. Typical Gate Trigger Current vs. Junction Temperature

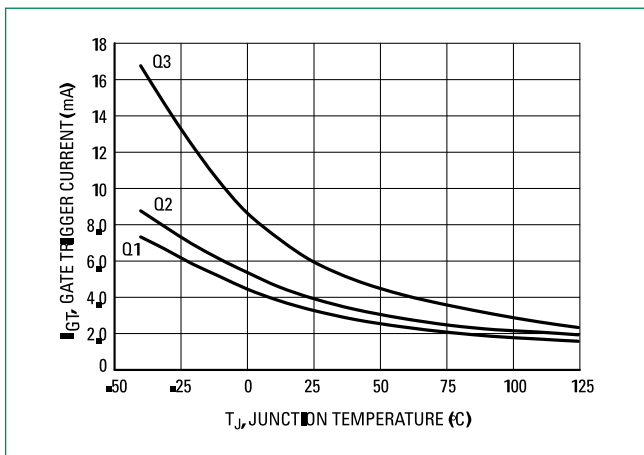


Figure 6. Typical Gate Trigger Voltage vs. Junction Temperature

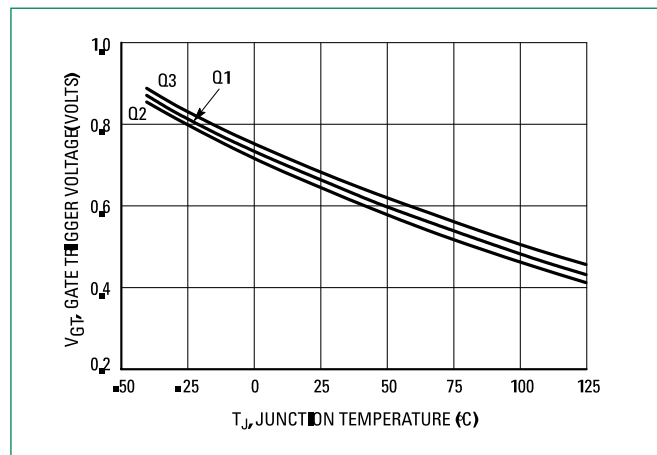


Figure 7. Typical Holding Current vs. Junction Temperature

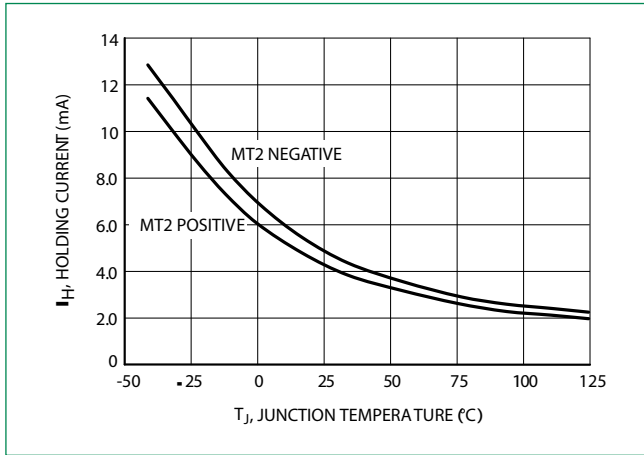


Figure 8. Typical Latching Current vs. Junction Temperature

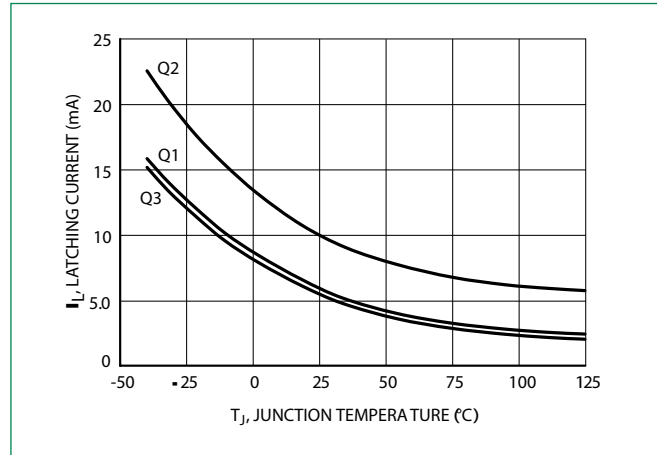


Figure 9. Exponential Static dv/dt vs. Gate-MT1 Resistance, MT2(+)

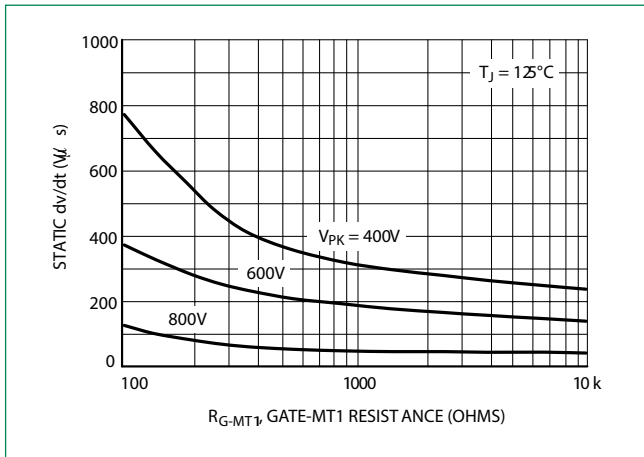


Figure 10. Exponential Static dv/dt vs. Gate-MT1 Resistance, MT2(-)

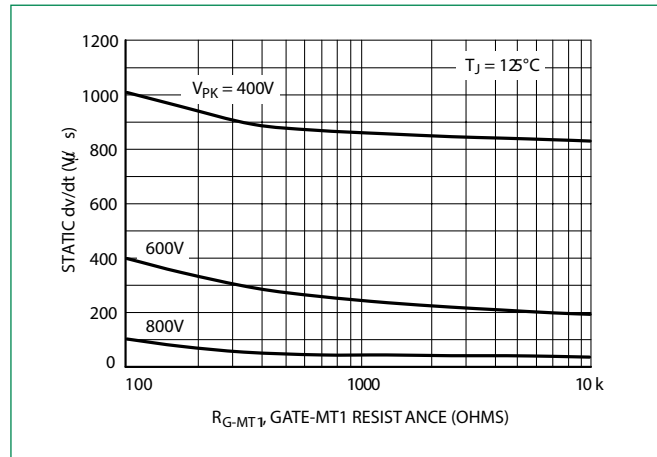


Figure 9. Exponential Static dv/dt vs. Gate-MT1 Resistance, MT2(+)

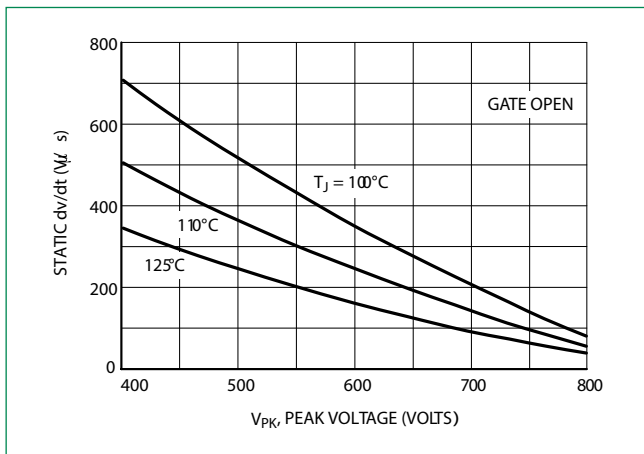


Figure 10. Exponential Static dv/dt vs. Gate-MT1 Resistance, MT2(-)

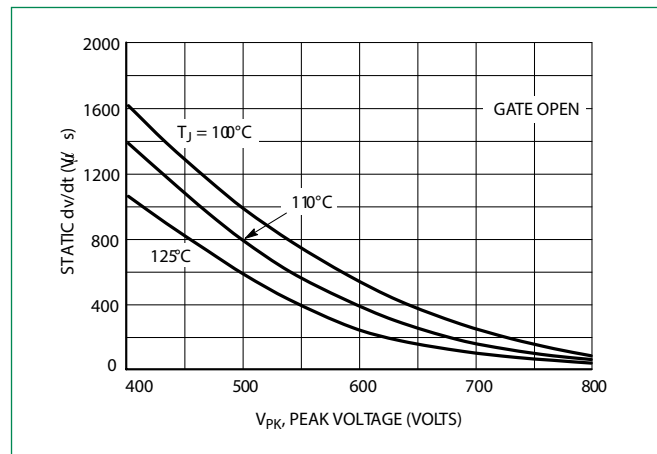


Figure 13. Typical Holding Current vs. Junction Temperature

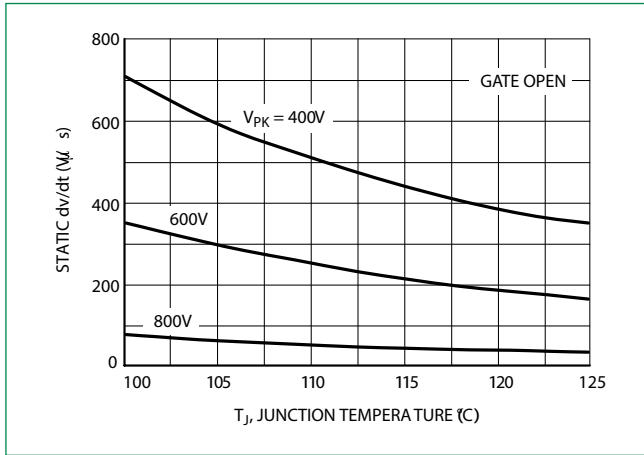


Figure 14. Typical Latching Current vs. Junction Temperature

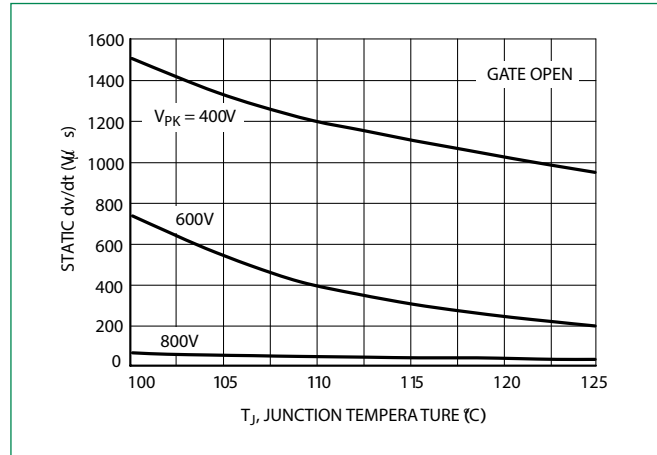


Figure 15. Typical Holding Current vs. Junction Temperature

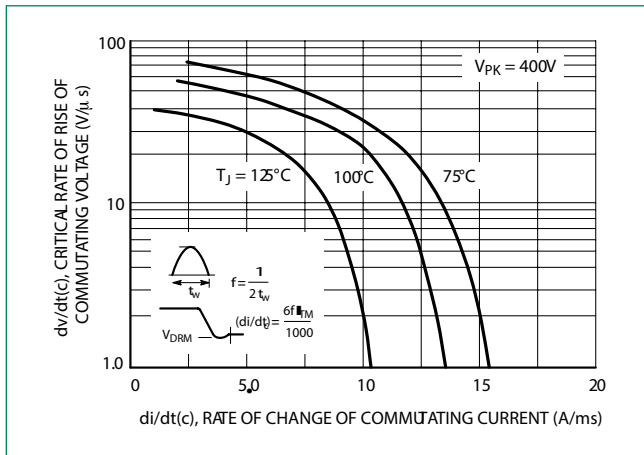
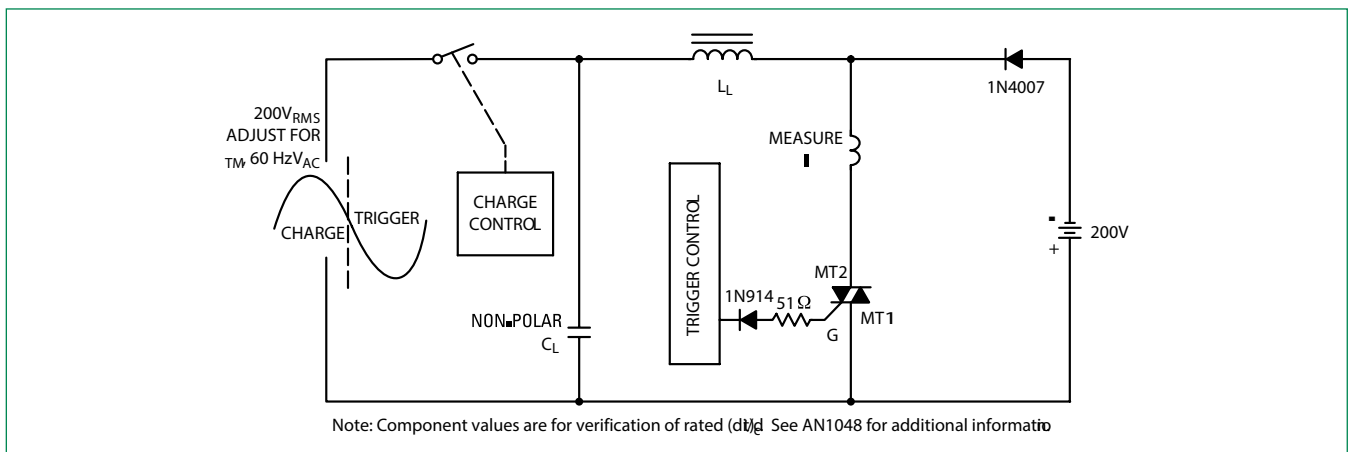
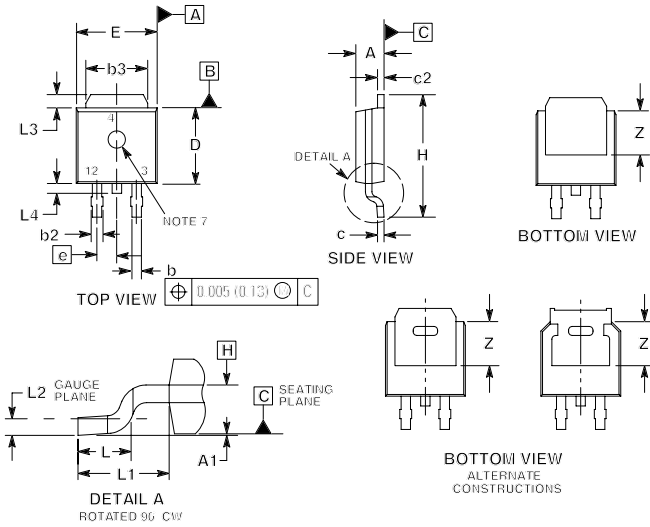


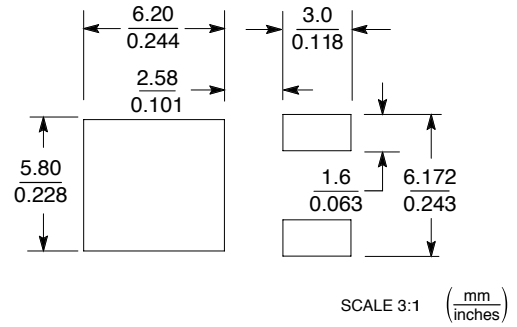
Figure 16. Simplified Test Circuit to Measure the Critical Rate of Rise of Commutating Current (di/dt)



Dimensions



Soldering Footprint



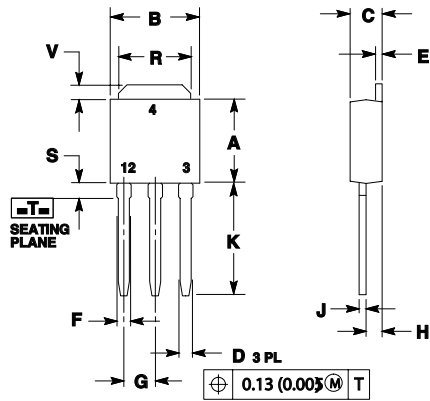
| Dim | Inches | | Millimeters | |
|-----|--------|-------|-------------|-------|
| | Min | Max | Min | Max |
| A | 0.087 | 0.094 | 2.20 | 2.40 |
| A1 | 0.000 | 0.005 | 0.00 | 0.12 |
| b | 0.022 | 0.030 | 0.55 | 0.75 |
| b2 | 0.026 | 0.033 | 0.65 | 0.85 |
| b3 | 0.209 | 0.217 | 5.30 | 5.50 |
| c | 0.019 | 0.023 | 0.49 | 0.59 |
| c2 | 0.019 | 0.023 | 0.49 | 0.59 |
| D | 0.213 | 0.224 | 5.40 | 5.70 |
| E | 0.252 | 0.260 | 6.40 | 6.60 |
| e | 0.091 | | 2.30 | |
| H | 0.374 | 0.406 | 9.50 | 10.30 |
| L | 0.058 | 0.070 | 1.47 | 1.78 |
| L1 | 0.114 | | 2.90 | |
| L2 | 0.019 | 0.023 | 0.49 | 0.59 |
| L3 | 0.053 | 0.065 | 1.35 | 1.65 |
| L4 | 0.028 | 0.039 | 0.70 | 1.00 |
| Z | 0.154 | - | 3.90 | - |

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

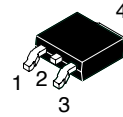
- STYLE 6:
PIN 1. MT1
2. MT2
3. GATE
4. MT2

Dimensions

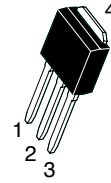
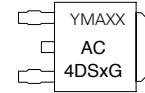
DPAK-3
CASE 369D-01
ISSUE B



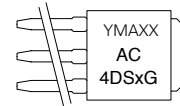
Part Marking System



DPAK
CASE 369C
STYLE 6



DPAK-3
CASE 369D
STYLE 6



AC4DCx =Device Code
x =M or N
Y =Year
M =Month
A =Assembly Site
XX =Lot Serial Code
G =Pb-Free Package

| Dim | Inches | | Millimeters | |
|-----|--------|-------|-------------|------|
| | Min | Max | Min | Max |
| A | 0.213 | 0.224 | 5.40 | 5.70 |
| B | 0.252 | 0.260 | 6.40 | 6.60 |
| C | 0.087 | 0.094 | 2.20 | 2.40 |
| D | 0.024 | 0.030 | 0.60 | 0.75 |
| E | 0.022 | 0.026 | 0.55 | 0.65 |
| F | 0.031 | 0.039 | 0.78 | 0.98 |
| G | 0.091 | | 2.30 | |
| H | 0.046 | 0.050 | 1.18 | 1.28 |
| J | 0.019 | 0.023 | 0.49 | 0.59 |
| K | 0.291 | 0.315 | 7.40 | 8.00 |
| R | 0.209 | 0.217 | 5.30 | 5.50 |
| S | 0.063 | | 1.60 | |
| V | 0.053 | 0.065 | 1.35 | 1.65 |
| Z | 0.150 | | 3.80 | |

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

2. CONTROLLING DIMENSION: INCH.

STYLE 6:
PIN 1. MT1
2. MT2
3. GATE
4. MT2

| Pin Assignment | |
|----------------|-----------------|
| 1 | Main Terminal 1 |
| 2 | Main Terminal 2 |
| 3 | Gate |
| 4 | Main Terminal 2 |

Ordering Information

| Device | Package Type | Package | Shipping |
|--------------|------------------|---------|--------------------|
| MAC4DSM-001 | DPAK-3 | 369D | 4000 Unit/Box |
| MAC4DSM-001G | DPAK-3 (Pb-Free) | 369D | 4000 Unit/Box |
| MAC4DSMT4 | DPAK-3 | 369C | 2500 / Tape & Reel |
| MAC4DSMT4G | DPAK-3 (Pb-Free) | 369C | 2500 / Tape & Reel |
| MAC4DSN-001 | DPAK-3 | 369D | 4000 Unit/Box |
| MAC4DSN-001G | DPAK-3 (Pb-Free) | 369D | 4000 Unit/Box |
| MAC4DSNT4 | DPAK-3 | 369C | 2500 / Tape & Reel |

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